# MBD701, MMBD701L, SMMBD701L

# **Silicon Hot-Carrier Diodes**

# **Schottky Barrier Diodes**

These devices are designed primarily for high–efficiency UHF and VHF detector applications. They are readily adaptable to many other fast switching RF and digital applications. They are supplied in an inexpensive plastic package for low–cost, high–volume consumer and industrial/commercial requirements. They are also available in a Surface Mount package.

#### Features

- Extremely Low Minority Carrier Lifetime 15 ps (Typ)
- Very Low Capacitance 1.0 pF @  $V_R = 20 V$
- High Reverse Voltage to 70 V
- Low Reverse Leakage 200 nA (Max)
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

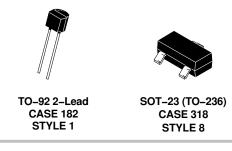
#### **MAXIMUM RATINGS** Symbol Rating Value Unit ٧ **Reverse Voltage** $V_R$ 70 Forward Power Dissipation $P_{F}$ @ T<sub>A</sub> = 25°C mW MBD701 280 MMBD701L, SMMBD701L 200 Derate above 25°C mW/°C **MBD701** 2.8 MMBD701L, SMMBD701L 2.0 **Operating Junction Temperature** ТJ -55 to +125 °C Range Storage Temperature Range T<sub>stg</sub> -55 to +150 °C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



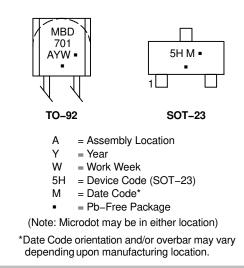
## **ON Semiconductor®**





TO-92		SOT-23		
2 0-4	—• 1	3 0	<b>⊢</b> • 1	
CATHODE	ANODE	CATHODE	ANODE	

#### MARKING DIAGRAMS



#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

# MBD701, MMBD701L, SMMBD701L

#### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Breakdown Voltage $(I_R = 10 \ \mu Adc)$	V <sub>(BR)R</sub>	70	-	_	V
Total Capacitance $(V_R = 20 V, f = 1.0 MHz)$ Figure 1	CT	-	0.5	1.0	pF
Reverse Leakage (V <sub>R</sub> = 35 V) Figure 3	I <sub>R</sub>	-	9.0	200	nAdc
Forward Voltage (I <sub>F</sub> = 1.0 mAdc) Figure 4	V <sub>F</sub>	-	0.42	0.5	Vdc
Forward Voltage (I <sub>F</sub> = 10 mAdc) Figure 4	V <sub>F</sub>	-	0.7	1.0	Vdc

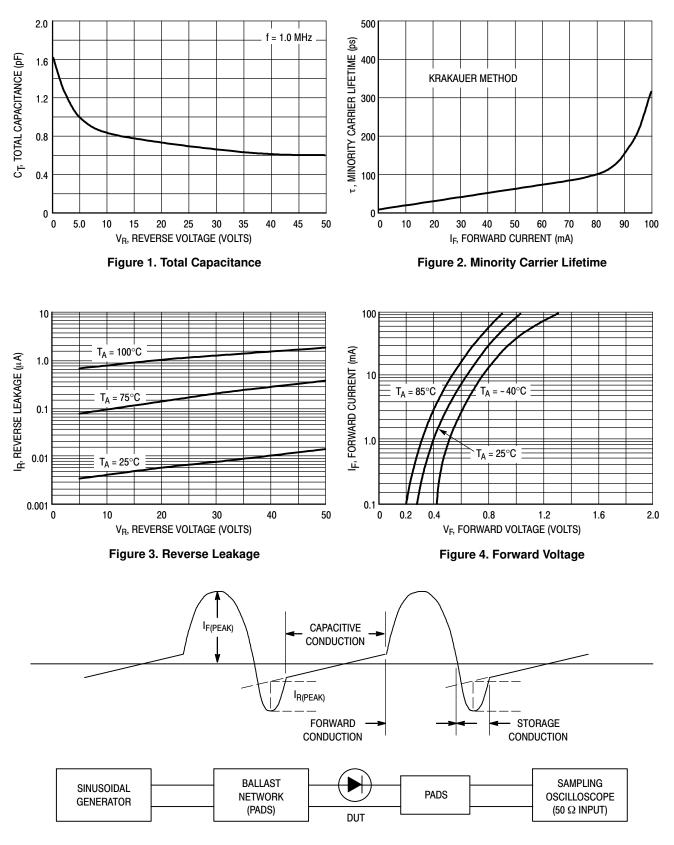
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

#### **ORDERING INFORMATION**

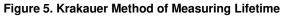
Device	Package	Shipping <sup>†</sup>
MBD701G	TO–92 (Pb–Free)	1,000 Units / Bulk
MMBD701LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel
SMMBD701LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel
MMBD701LT3G	SOT-23 (Pb-Free)	10,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

### MBD701, MMBD701L, SMMBD701L



#### **TYPICAL ELECTRICAL CHARACTERISTICS**

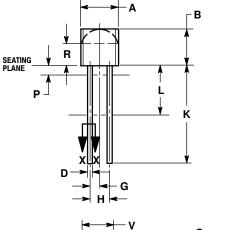


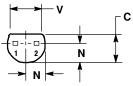
### PACKAGE DIMENSIONS

TO-92 (TO-226AC) CASE 182-06 ISSUE L

D

SECTION X-X





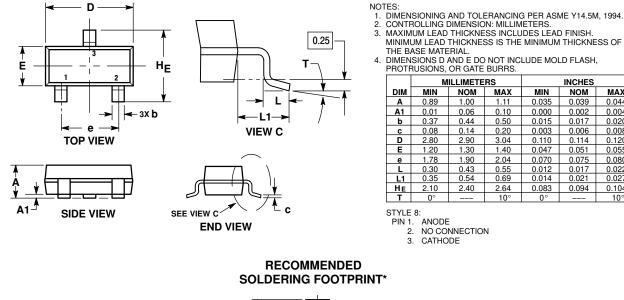
- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. CONTOUR OF PACKAGE BEYOND ZONE R IS UNCONTROLLED. 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

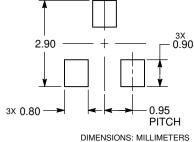
	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.21
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.050 BSC		1.27 BSC	
Η	0.100 BSC		2.54 BSC	
ſ	0.014	0.016	0.36	0.41
Κ	0.500		12.70	
L	0.250		6.35	
Ν	0.080	0.105	2.03	2.66
Ρ		0.050		1.27
R	0.115		2.93	
٧	0.135		3.43	

STYLE 1: PIN 1. ANODE 2. CATHODE

#### PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AR** 





\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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INCHES

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